

	<p>NTD6416ANL-1G</p>
	<p>Hersteller-Teilenummer: NTD6416ANL-1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 100V 19A IPAK</p> <p>Datenblätter:  NTD6416ANL-1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 2088 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD6416ANL-1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 100V 19A IPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2088 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-251-3 Short Leads, IPak, TO-251AA
Supplier Device-Gehäuse	I-Pak
Verlustleistung (max)	71W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)
Rds On (Max) @ Id, Vgs	74 mOhm @ 19A, 10V
VGS (th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1000pF @ 25V
Verpackung	Tube



















































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Sie können auch interessiert sein:

 <p>NTD6416ANLT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 19A DPAK</p>	 <p>NTD6416ANG ON NTD6416ANG ON</p>	 <p>NTD6416ANT4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 17A DPAK</p>	 <p>NTD6416ANL ON NTD6416ANL ON</p>
 <p>NTD6416AN-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 17A IPAK</p>	 <p>NTD6416AN ON NTD6416AN ON</p>	 <p>NTD65N03G ON NTD65N03G ON</p>	 <p>NTD6416ANL4G ON ON TO252</p>

heiße Teile

Mehr

 NTD60N02R-035	 NTD60N02R-1G	 NTD60N02R-1R	 NTD60N02R-35G	 NTD60N02RG
 NTD60N02RG-1G	 NTD60N02RT	 NTD60N02RT4	 NTD60N02RT4G	 NTD60N03RT4G
 NTD60N03T4	 NTD60N03T4G	 NTD6414AN	 NTD6414AN-1G	 NTD6414ANT4G
 NTD6414AUG	 NTD6415AN	 NTD6415AN-1G	 NTD6415ANL	 NTD6415ANLT4G
 NTD6415ANT4G	 NTD6416AN	 NTD6416AN-1G	 NTD6416ANG	 NTD6416ANL
 NTD6416ANLT4G	 NTD6416ANT4G	 NTD65N03G	 NTD65N03R-001	 NTD65N03R-035
 NTD65N03R-1G	 NTD65N03R-35G	 NTD65N03RG	 NTD65N03RT4G	 NTD6600G
 NTD6600N	 NTD6600N-001	 NTD6600N-1G	 NTD6600NT4	 NTD6600NT4G
 NTD70N03	 NTD70N03R	 NTD70N03R-001	 NTD70N03R-1	 NTD70N03R-1G
 NTD70N03RG	 NTD70N03RT4	 NTD70N03RT4G	 NTD70N03TR4	 NTD78N03

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